- Preface to the Second Edition p. v
- Preface to the First Edition p. vii
- 1 Ceramic Fabrication Processes: An Introductory Overview p. 1
- 1.1 Introduction p. 1
- 1.2 Ceramic Fabrication Processes p. 3
- 1.3 Production of Polycrystalline Ceramics from Powders: An Overview p. 28
- 1.4 A Case Study in Processing: The Fabrication of TiO[subscript 2] from Powders p. 41
- 1.5 Concluding Remarks p. 43
- Problems p. 44
- References p. 45
- 2 Synthesis of Powders p. 49
- 2.1 Introduction p. 49
- 2.2 Desirable Powder Characteristics p. 49
- 2.3 Powder Synthesis Methods p. 51
- 2.4 Powder Preparation by Mechanical Methods p. 52
- 2.5 Powder Synthesis by Chemical Methods p. 62
- 2.6 Concluding Remarks p. 118
- Problems p. 118
- References p. 120
- 3 Powder Characterization p. 125
- 3.1 Introduction p. 125
- 3.2 Physical Characterization p. 126
- 3.3 Chemical Composition p. 156
- 3.4 Crystal Structure and Phase Composition p. 162
- 3.5 Surface Characterization p. 164
- 3.6 Concluding Remarks p. 176
- Problems p. 177
- References p. 179
- 4 Science of Colloidal Processing p. 181
- 4.1 Introduction p. 181
- 4.2 Types of Colloids p. 183
- 4.3 Attractive Surface Forces p. 183
- 4.4 Stabilization of Colloidal Suspensions p. 190
- 4.5 Electrostatic Stabilization p. 191
- 4.6 Steric Stabilization p. 211
- 4.7 Electrosteric Stabilization p. 222
- 4.8 Structure of Consolidated Colloids p. 227
- 4.9 Rheology of Colloidal Suspensions p. 230
- 4.10 Concluding Remarks p. 242
- Problems p. 243
- References p. 245
- 5 Sol-Gel Processing p. 248
- 5.1 Introduction p. 248
- 5.2 Types of Gels p. 250
- 5.3 Sol-Gel Processing of Aqueous Silicates p. 254

- 5.4 Metal Alkoxides p. 260
- 5.5 Sol-Gel Processing of Silicon Alkoxides p. 266
- 5.6 Sol-Gel Preparation Techniques p. 305
- 5.7 Applications of Sol-Gel Processing p. 315
- 5.8 Concluding Remarks p. 323
- Problems p. 323
- References p. 324
- 6 Powder Consolidation and Forming of Ceramics p. 328
- 6.1 Introduction p. 328
- 6.2 Packing of Particles p. 330
- 6.3 Additives and Ceramic Forming p. 344
- 6.4 Forming of Ceramics p. 360
- 6.5 Drying of Granular Ceramics p. 405
- 6.6 Binder Removal p. 409
- 6.7 Green Microstructures and Their Characterization p. 418
- 6.8 Concluding Remarks p. 418
- Problems p. 419
- References p. 421
- 7 Sintering of Ceramics: Fundamentals p. 425
- 7.1 Introduction p. 425
- 7.2 Driving Force for Sintering p. 427
- 7.3 Defects in Crystalline Solids p. 428
- 7.4 Diffusion in Crystalline Solids p. 441
- 7.5 Chemical Potential p. 451
- 7.6 Diffusional Flux Equations p. 459
- 7.7 Vapor Pressure Over a Curved Surface p. 461
- 7.8 Diffusion in Ionic Crystals: Ambipolar Diffusion p. 462
- 7.9 Concluding Remarks p. 466
- Problems p. 467
- References p. 468
- 8 Theory of Solid-State and Viscous Sintering p. 470
- 8.1 Introduction p. 470
- 8.2 Mechanisms of Sintering p. 471
- 8.3 Effects of Grain Boundaries p. 473
- 8.4 Theoretical Analysis of Sintering p. 476
- 8.5 Scaling Laws p. 477
- 8.6 Analytical Models p. 482
- 8.7 Numerical Simulation of Sintering p. 506
- 8.8 Phenomenological Sintering Equations p. 510
- 8.9 Sintering Diagrams p. 511
- 8.10 Sintering with an Externally Applied Pressure p. 514
- 8.11 The Stress Intensification Factor p. 522
- 8.12 The Sintering Stress p. 524
- 8.13 Measurement of the Sintering Stress and Stress Intensification Factor p. 527
- 8.14 Alternative Derivation of the Sintering Equations p. 530
- 8.15 Concluding Remarks p. 535

- Problems p. 536
- References p. 537
- 9 Grain Growth and Microstructure Control p. 540
- 9.1 Introduction p. 540
- 9.2 General Features of Grain Growth p. 541
- 9.3 Ostwald Ripening: The LSW Theory p. 546
- 9.4 Topological and Interfacial Tension Requirements p. 554
- 9.5 Normal Grain Growth in Dense Solids p. 556
- 9.6 Abnormal Grain Growth in Dense Solids p. 567
- 9.7 Mechanisms Controlling the Boundary Mobility p. 573
- 9.8 Grain Growth and Pore Evaluation in Porous Solids p. 585
- 9.9 Simultaneous Densification and Grain Growth p. 602
- 9.10 Fabrication Principles for Ceramics with Controlled Microstructure p. 611
- 9.11 Concluding Remarks p. 614
- Problems p. 615
- References p. 616
- 10 Liquid-Phase Sintering p. 620
- 10.1 Introduction p. 620
- 10.2 Elementary Features of Liquid-Phase Sintering p. 622
- 10.3 Stages of Liquid-Phase Sintering p. 624
- 10.4 Thermodynamic and Kinetic Factors p. 627
- 10.5 Grain Boundary Films p. 639
- 10.6 The Basic Mechanisms of Liquid-Phase Sintering p. 646
- 10.7 Hot Pressing with a Liquid Phase p. 670
- 10.8 Use of Phase Diagrams in Liquid-Phase Sintering p. 671
- 10.9 Activated Sintering p. 677
- 10.10 Vitrification p. 678
- 10.11 Concluding Remarks p. 682
- Problems p. 684
- References p. 685
- 11 Special Topics in Sintering p. 688
- 11.1 Introduction p. 688
- 11.2 Rayleigh Instability and Microstructural Evolution p. 689
- 11.3 Inhomogeneities and Their Effects on Sintering p. 693
- 11.4 Constrained Sintering I: Rigid Inclusions p. 702
- 11.5 Constrained Sintering II: Adherent Thin Films and Multilayers p. 723
- 11.6 Thin Films: Grain Growth and Dimensional Stability p. 733
- 11.7 Solid Solution Additives and the Sintering of Ceramics p. 739
- 11.8 Sintering with Chemical Reaction: Reaction Sintering p. 754
- 11.9 Viscous Sintering with Crystallization p. 763
- 11.10 Concluding Remarks p. 773
- Problems p. 774
- References p. 775
- 12 Densification Process Variables and Densification Practice p. 779
- 12.1 Introduction p. 779
- 12.2 Conventional Sintering p. 780

- 12.3 Microwave Sintering p. 818
- 12.4 Pressure Sintering p. 829
- 12.5 Concluding Remarks p. 841
- Problems p. 841
- References p. 843
- Appendix A Physical Constants p. 847
- Appendix B SI Units--Names and Symbols p. 849
- Appendix C Conversion of Units and Decimal Fractions and Multiples p. 851
- Appendix D Ionic Crystal Radii (in units of 10[superscript -10] m) p. 853
- Appendix E Density and Melting Point of Some Elements, Ceramics, and Minerals p. 855
- Appendix F Aperture Size of U.S. Standard Wire Mesh Sieves (ASTM E 11:87) p. 859
- Index p. 861